



Improved Quad CMOS Analog Switches

DESCRIPTION

The DG308B, DG309B analog switches are highly improved versions of the industry-standard DG308A, DG309. These devices are fabricated in Vishay Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc.

An improved charge injection compensation design minimizes switching transients. The DG308B and DG309B can handle up to ± 22 V input signals. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

The DG308B is a normally open switch and the DG309B is a normally closed switch. (see Truth Table.)

FEATURES

- ± 22 V supply voltage rating
- CMOS compatible logic
- Low on-resistance - $R_{DS(on)}$: 45 Ω
- Low leakage - $I_{D(on)}$: 20 pA
- Single supply operation possible
- Extended temperature range
- Fast switching - t_{ON}: < 200 ns
- Low glitching - Q: 1 pC

Pb-free Available

RoHS* COMPLIANT

BENEFITS

- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Superior to DG308A, DG309
- Space savings (TSSOP)

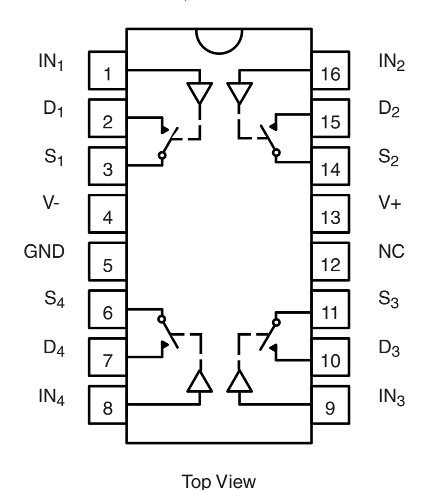
APPLICATIONS

- Industrial instrumentation
- Test equipment
- Communications systems
- Disk drives
- Computer peripherals
- Portable instruments
- Sample-and-hold circuits

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG308B

Dual-In-Line, SOIC and TSSOP



Top View

TRUTH TABLE

Logic	DG308B	DG309B
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 3.5 V
Logic "1" ≥ 11 V

* Pb containing terminations are not RoHS compliant, exemptions may apply



ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	16-Pin PlasticDIP	DG308BDJ DG308BDJ-E3
		DG309BDJ DG309BDJ-E3
	16-Pin Narrow SOIC	DG308BDY DG308BDY-E3 DG308BDY-T1 DG308BDY-T1-E3
		DG309BDY DG309BDY-E3 DG309BDY-T1 DG309BDY-T1-E3
	16-Pin TSSOP	DG308BDQ DG308BDQ-E3 DG308BDQ-T1 DG308BDQ-T1-E3
		DG309BDQ DG309BDQ-E3 DG309BDQ-T1 DG309BDQ-T1-E3

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
Voltages Referenced, V+ to V-		44	V
GND		25	
Digital Inputs[a], V_S, V_D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature	(AK Suffix)	- 65 to 150	°C
	(DJ, DY and DQ Suffix)	- 65 to 125	
Power Dissipation (Package)[b]	16-Pin Plastic DIP[c]	470	mW
	16-Pin Narrow SOIC and TSSOP[d]	640	
	16-Pin CerDIP[e]	900	

Notes:
a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 6.5 mW/°C above 75 °C.
d. Derate 7.6 mW/°C above 75 °C.
e. Derate 12 mW/°C above 75 °C.

SPECIFICATIONS[a]									
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		
Parameter	Symbol	V+ = 15 V, V- = - 15 V, V_{IN} = 11 V, 3.5 V[f]	Temp.[b]	Typ.[c]	Min.[d]	Max.[d]	Min.[d]	Max.[d]	Unit
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	$R_{DS(on)}$	V_D = ± 10 V, I_S = 1 mA	Room Full	45		85 100		85 100	Ω
$R_{DS(on)}$ Match	$\Delta R_{DS(on)}$	V_D = ± 10 V, I_S = 1 mA	Room	2					%
Source Off Leakage Current	$I_{S(off)}$	V_S = ± 14 V, V_D = ± 14 V	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	nA
Drain Off Leakage Current	$I_{D(off)}$	V_D = ± 14 V, V_S = ± 14 V	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	nA
Drain On Leakage Current	$I_{D(on)}$	V_S = V_D = ± 14 V	Room Full	± 0.02	- 0.5 - 40	0.5 40	- 0.5 - 10	0.5 10	nA
Digital Control									
Input, Voltage High	V_{INH}		Full		11		11		V
Input, Voltage Low	V_{INL}		Full			3.5		3.5	V
Input Current	I_{INH} or I_{INL}	V_{INH} or V_{INL}	Full		- 1	1	- 1	1	µA
Input Capacitance	C_{IN}		Room	5					pF
Dynamic Characteristics									
Turn-On Time	t_{ON}	V_S = 3 V, see figure 2	Room			200		200	ns
Turn-Off Time	t_{OFF}	V_S = 3 V, see figure 2	Room			150		150	ns
Charge Injection	Q	C_L = 1000 pF, V_g = 0 V, R_g = 0 Ω	Room	1					pC
Source-Off Capacitance	$C_{S(off)}$	V_S = 0 V, f = 1 MHz,	Room	5					pF
Drain-Off Capacitance	$C_{D(off)}$	V_S = 0 V, f = 1 MHz,	Room	5					pF
Channel-On Capacitance	$C_{D(on)}$	V_D = V_S = 0 V, f = 1 MHz	Room	16					pF
Off-Isolation	OIRR	C_L = 15 pF, R_L = 50 Ω, V_S = 1 V_{RMS}, f = 100 kHz	Room	90					dB
Channel-to-Channel Crosstalk	X_{TALK}	C_L = 15 pF, R_L = 50 Ω, V_S = 1 V_{RMS}, f = 100 kHz	Room	95					dB
Power Supply									
Positive Supply Current	I+	V_{IN} = 0 V or 15 V	Room Full			1 5		1 5	µA
Negative Supply Current	I-	V_{IN} = 0 V or 15 V	Room Full		- 1 - 5		- 1 - 5		µA
Power Supply Range for Continuous Operation	V_{OP}		Full		± 4	± 22	± 4	± 22	V

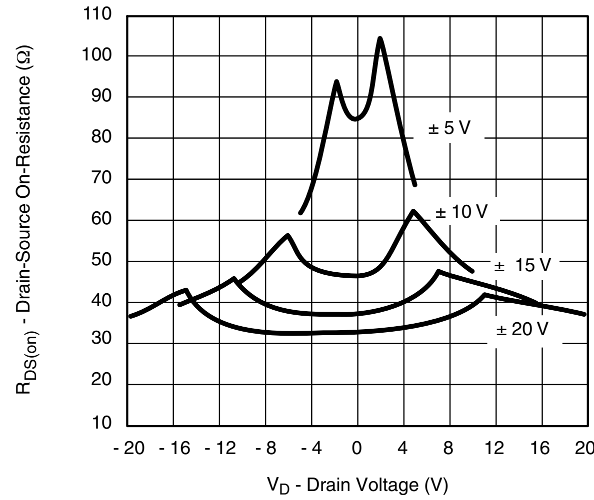


SPECIFICATIONS[a] (for Single Supply)									
Parameter	**Symbol**	**Test Conditions Unless Specified** $V+ = 12$ V, $V- = 0$ V $V_{IN} = 11$ V, 3.5 V[f]	**Temp.**[b]	**Typ.**[c]	**A Suffix** - 55 °C to 125 °C **Min.**[d]	**A Suffix** **Max.**[d]	**D Suffix** - 40 °C to 85 °C **Min.**[d]	**D Suffix** **Max.**[d]	**Unit**
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_D = 3$ V, 8 V, $I_S = 1$ mA	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t_{ON}	$V_S = 8$ V, see figure 2	Room			300		300	ns
Turn-Off Time	t_{OFF}		Room			200		200	
Charge Injection	Q	$C_L = 1$ nF, $V_{gen} = 6$ V, $R_{gen} = 0$ Ω	Room	4					pC
Power Supply									
Positive Supply Current	I+	$V_{IN} = 0$ V or 12 V	Room Full			1 5		1 5	µA
Negative Supply Current	I-		Room Full		- 1 - 5		- 1 - 5		
Power Supply Range for Continuous Operation	V_{OP}		Full		4	44	4	44	V

Notes:
a. Refer to PROCESS OPTION FLOWCHART .
b. Room = 25 °C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

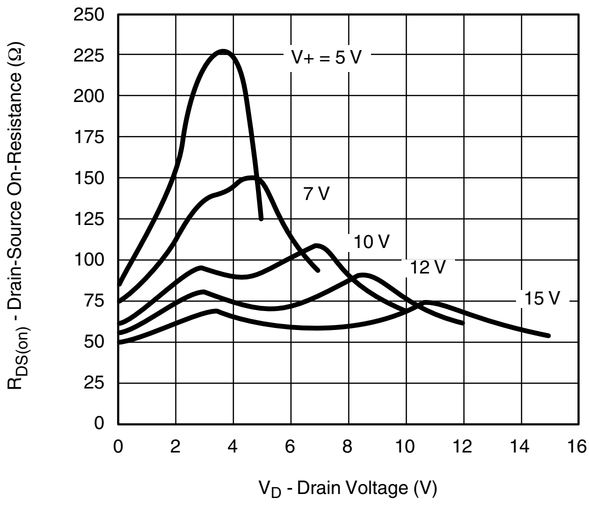
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



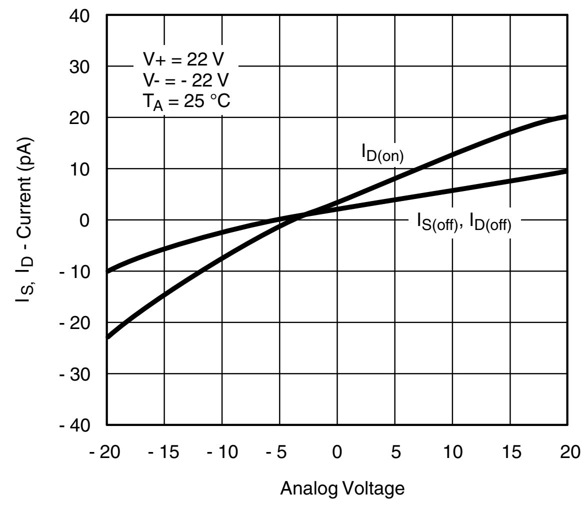
$R_{DS(on)}$ vs. V_D and Power Supply Voltages

100
90
80
70
60
50
40
30
20
10
0
- 15
- 10
- 5
0
5
10
15
V+ = 15 V
V- = - 15 V
125 °C
85 °C
25 °C
- 55 °C
RDS(on) - Drain-Source On-Resistance (Ω)
VD - Drain Voltage (V)

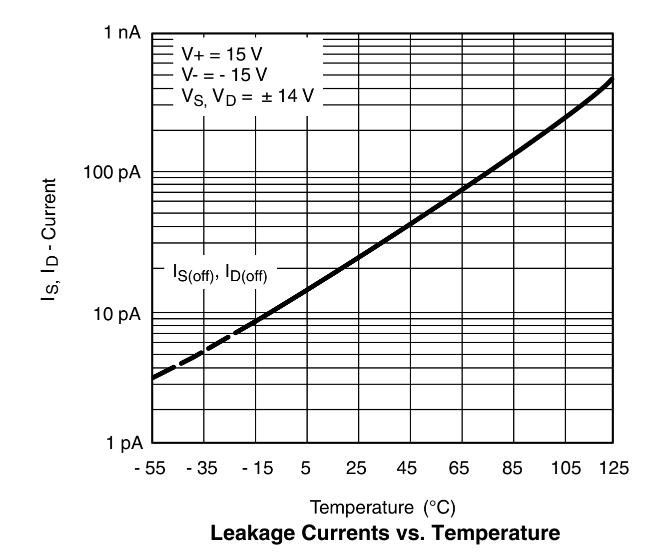
$R_{DS(on)}$ vs. V_D and Temperature



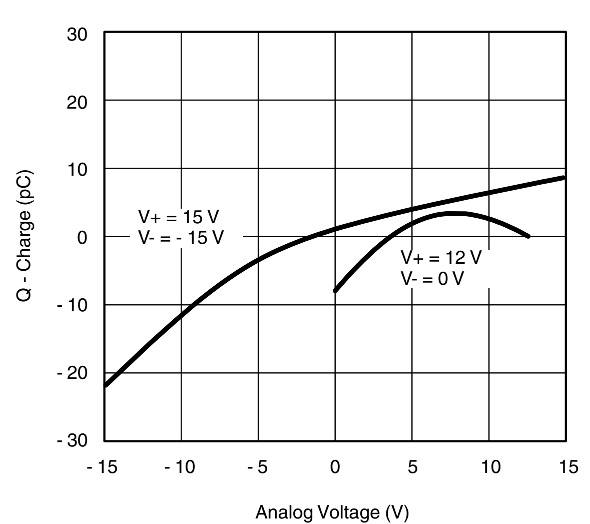
$R_{DS(on)}$ vs. V_D and Single Power Supply Voltages



Leakage Currents vs. Analog Voltage

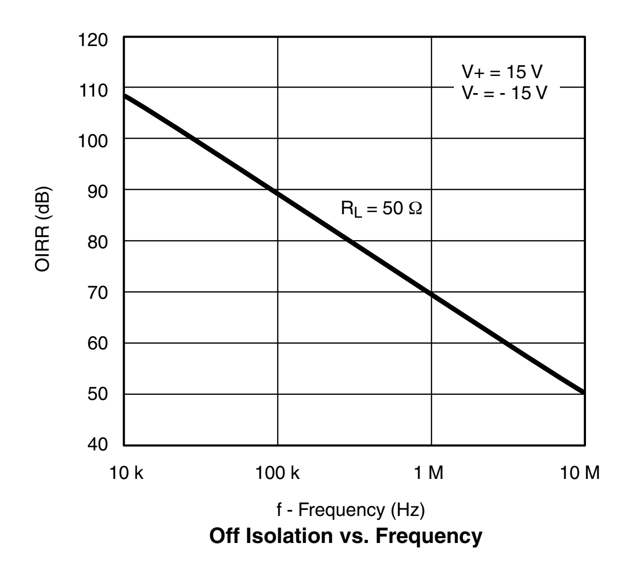


Leakage Currents vs. Temperature



Q_S, Q_D - Charge Injection vs. Analog Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Off Isolation vs. Frequency

SCHEMATIC DIAGRAM (Typical Channel)

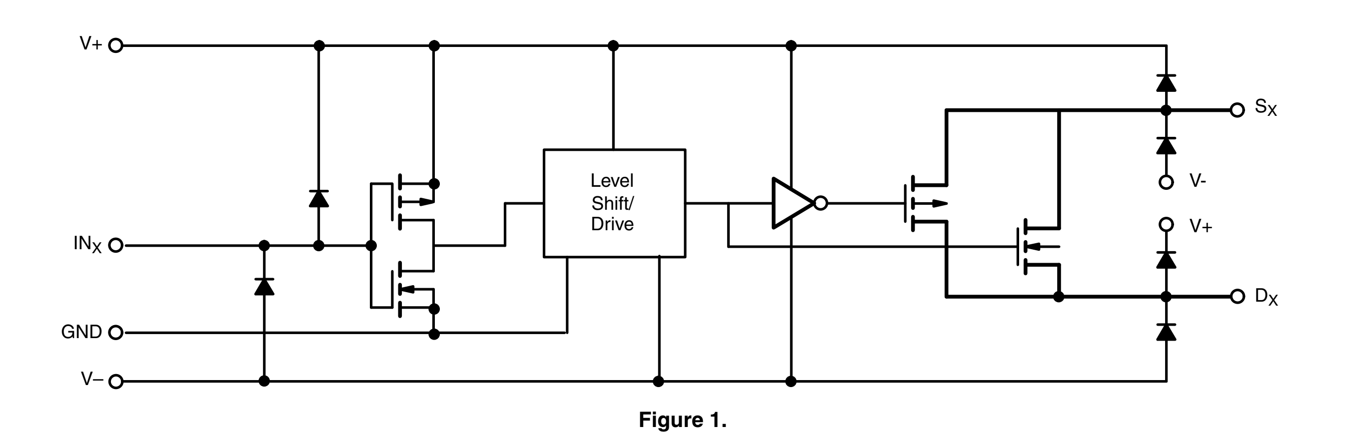


Figure 1.

TEST CIRCUITS

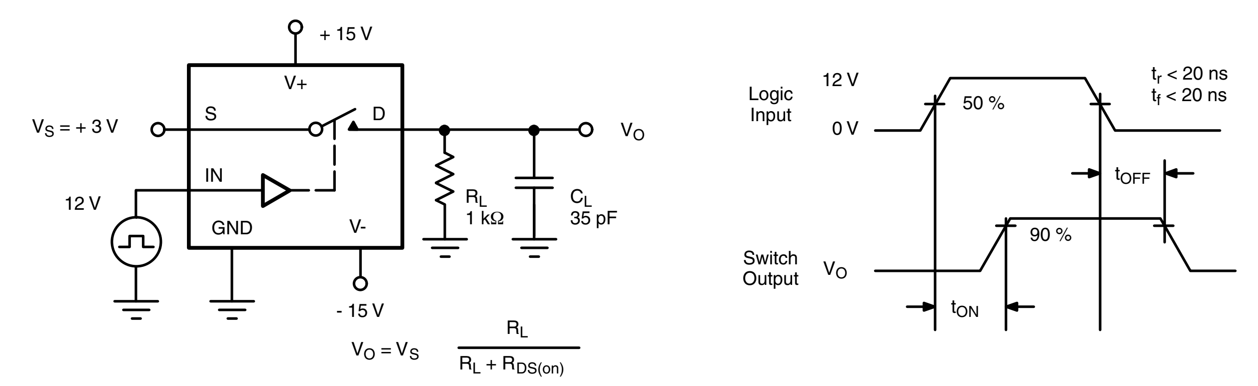


Figure 2. Switching Time

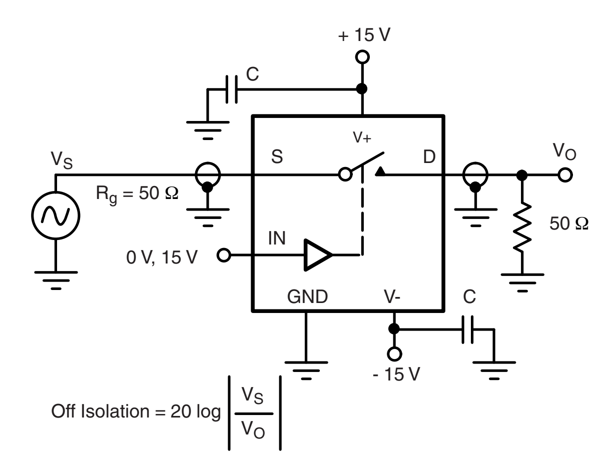


Figure 3. Off Isolation

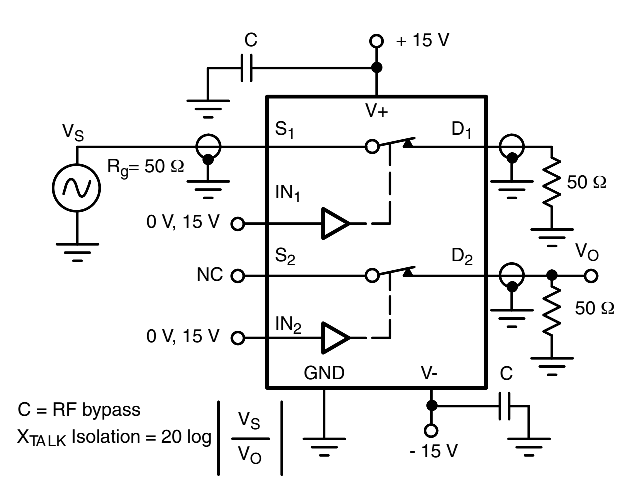
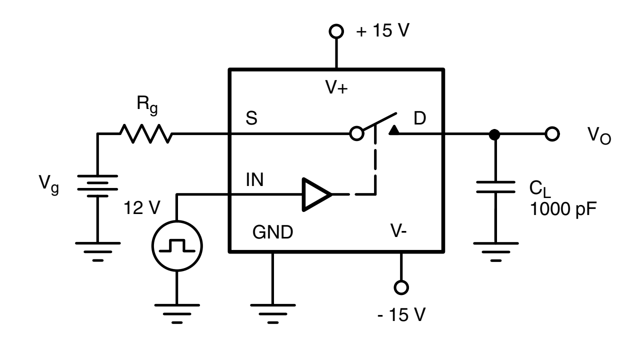
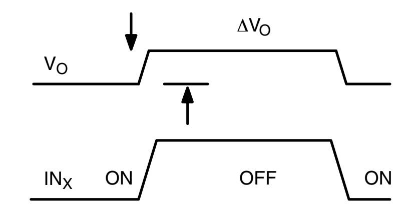


Figure 4. Channel-to-Channel Crosstalk





ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

Figure 5. Charge Injection

APPLICATIONS

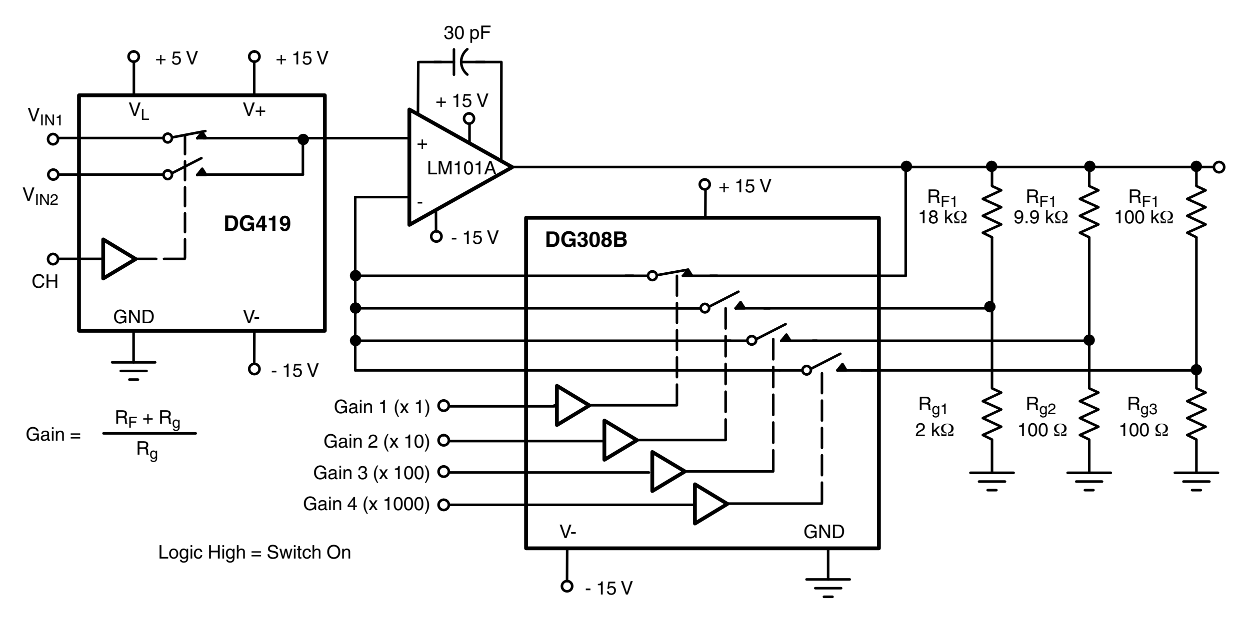


Figure 6. A Precision Amplifier with Digitally Programmable Inputs and Gains

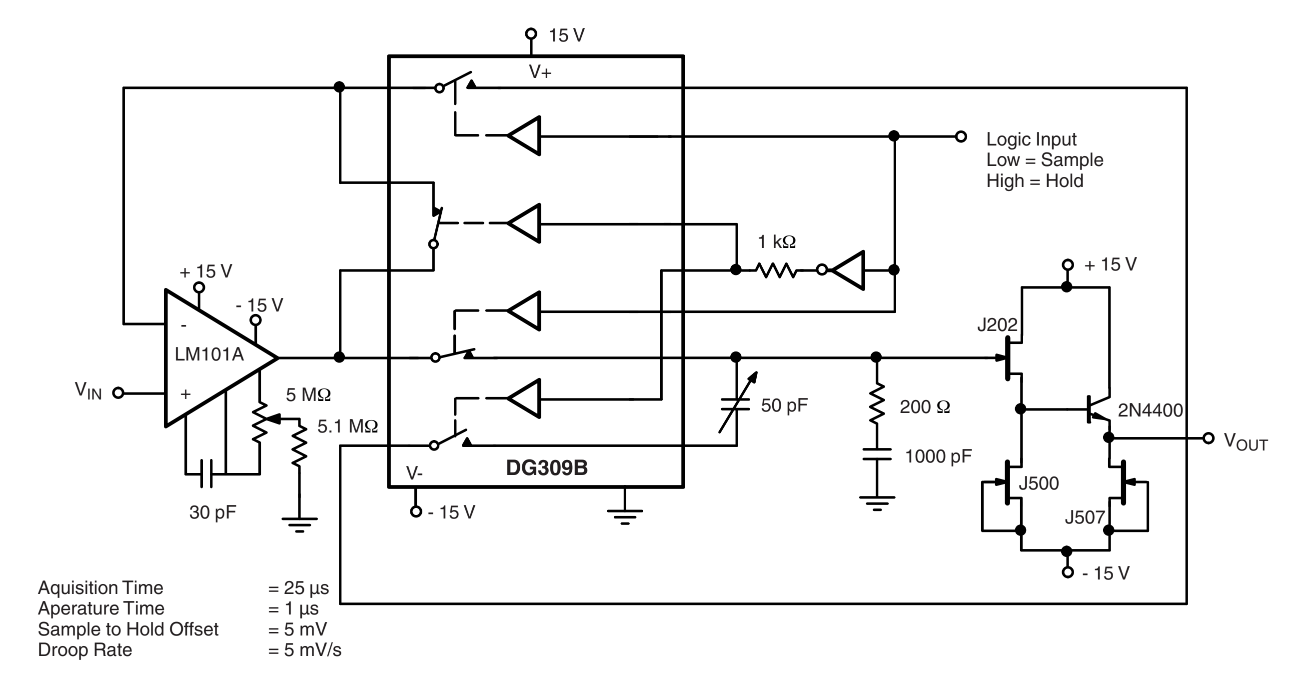
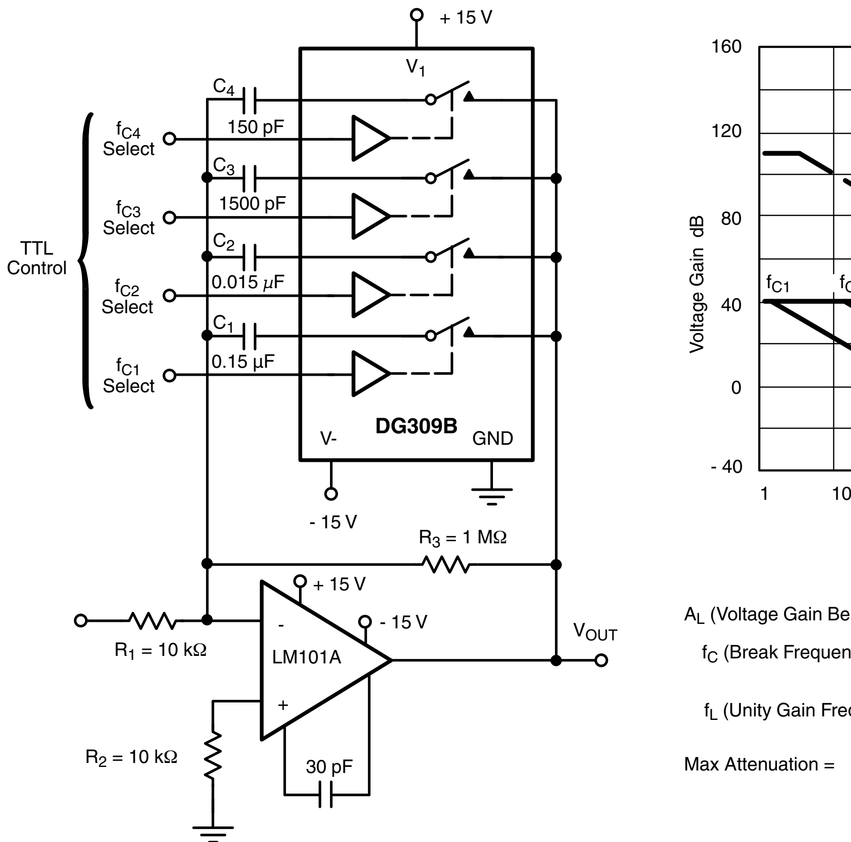
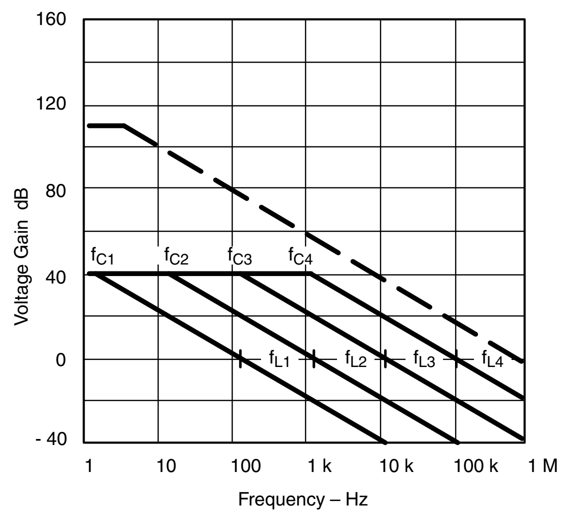


Figure 7. Sample-and-Hold

APPLICATIONS





A_L (Voltage Gain Below Break Frequency) = $\frac{R_3}{R_1}$ = 100 (40 dB)

f_C (Break Frequency) = $\frac{1}{2\pi R_3 C_X}$

f_L (Unity Gain Frequency) = $\frac{1}{2\pi R_1 C_X}$

Max Attenuation = $\frac{R_{DS(on)}}{10\ k\Omega} \approx$ - 40 dB

Figure 8. Active Low Pass Filter with Digitally Selected Break Frequency

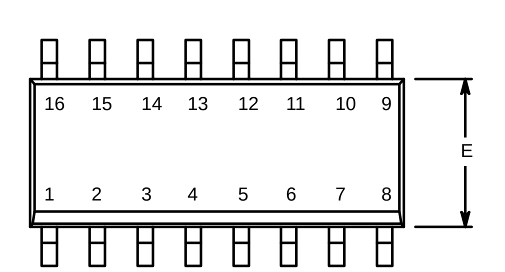
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70047.

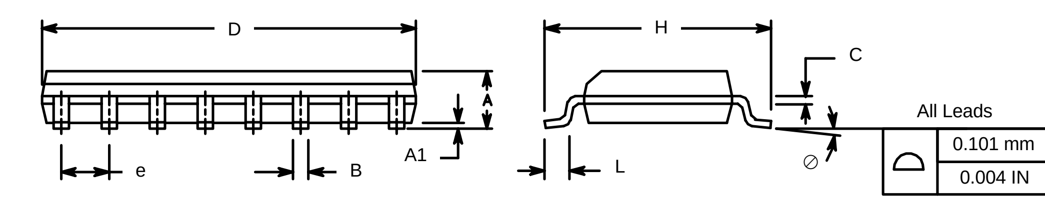


SOIC (NARROW): 16-LEAD

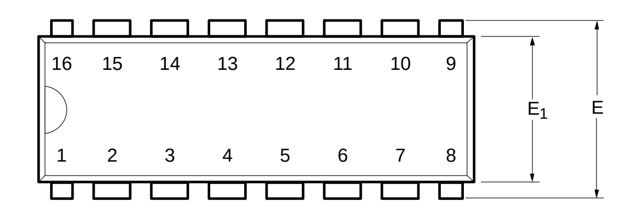
JEDEC Part Number: MS-012

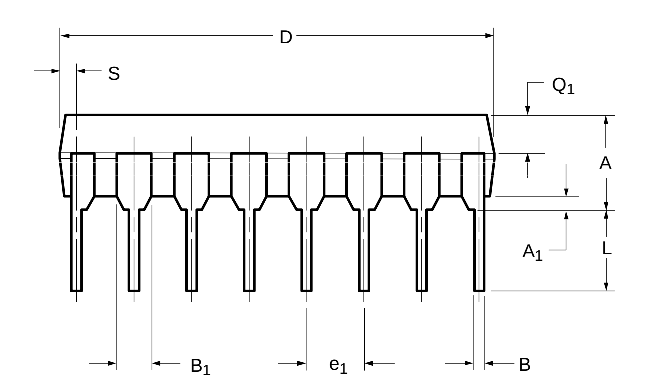
Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
∅	0°	8°	0°	8°
ECN: S-03946—Rev. F, 09-Jul-01 DWG: 5300				

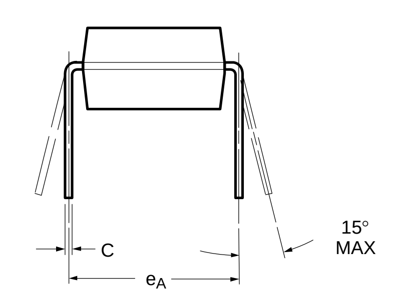




PDIP: 16-LEAD

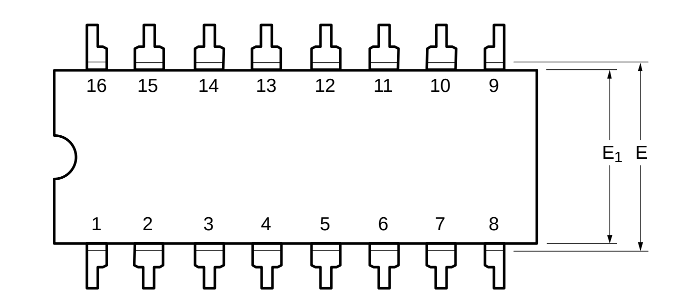


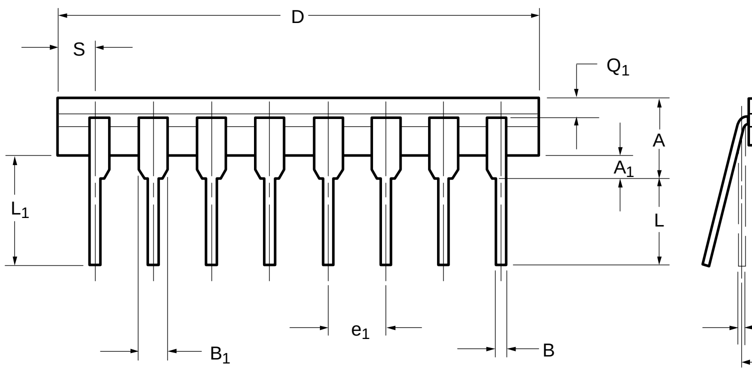


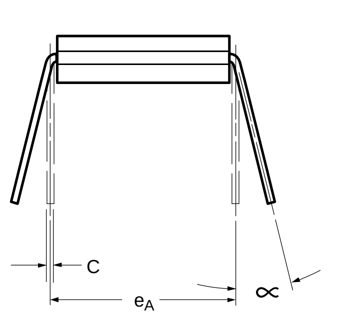


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A_1	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B_1	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E_1	5.59	7.11	0.220	0.280
e_1	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q_1	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482				

CERDIP: 16-LEAD



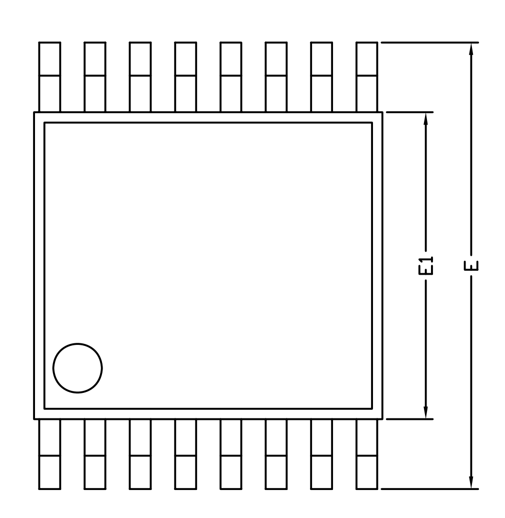


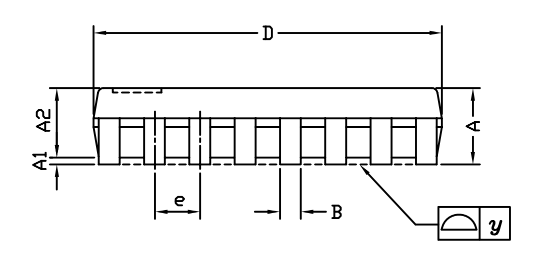


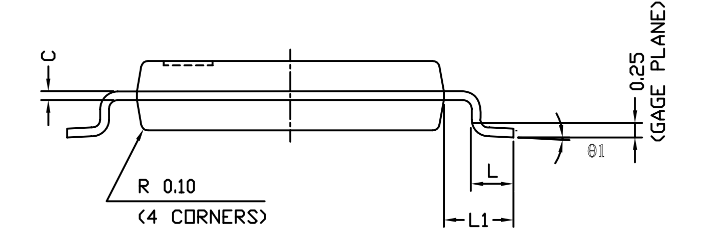
Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	4.06	5.08	0.160	0.200
A_1	0.51	1.14	0.020	0.045
B	0.38	0.51	0.015	0.020
B_1	1.14	1.65	0.045	0.065
C	0.20	0.30	0.008	0.012
D	19.05	19.56	0.750	0.770
E	7.62	8.26	0.300	0.325
E_1	6.60	7.62	0.260	0.300
e_1	2.54 BSC		0.100 BSC	
e_A	7.62 BSC		0.300 BSC	
L	3.18	3.81	0.125	0.150
L_1	3.81	5.08	0.150	0.200
Q_1	1.27	2.16	0.050	0.085
S	0.38	1.14	0.015	0.045
∝	0°	15°	0°	15°
ECN: S-03946—Rev. G, 09-Jul-01 DWG: 5403				



TSSOP: 16-LEAD

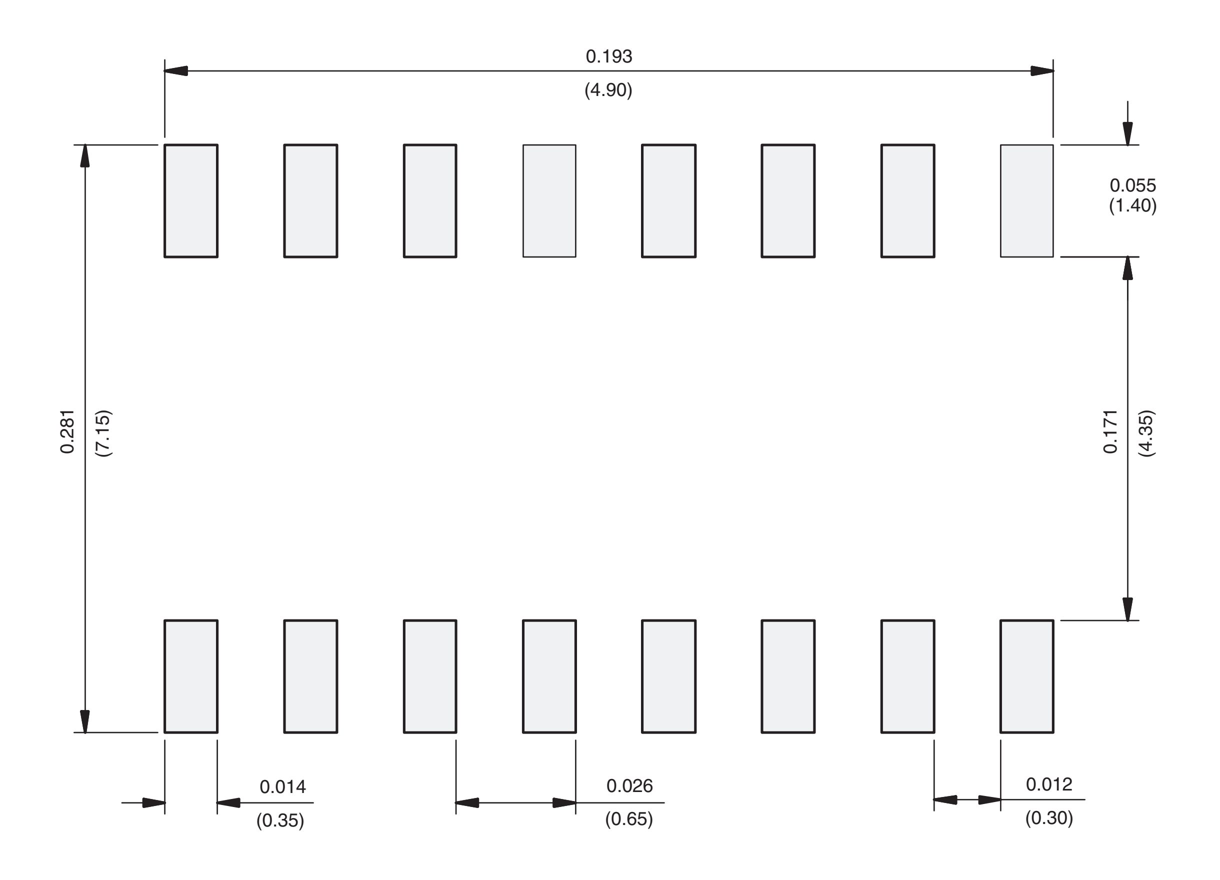






Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06 DWG: 5624			

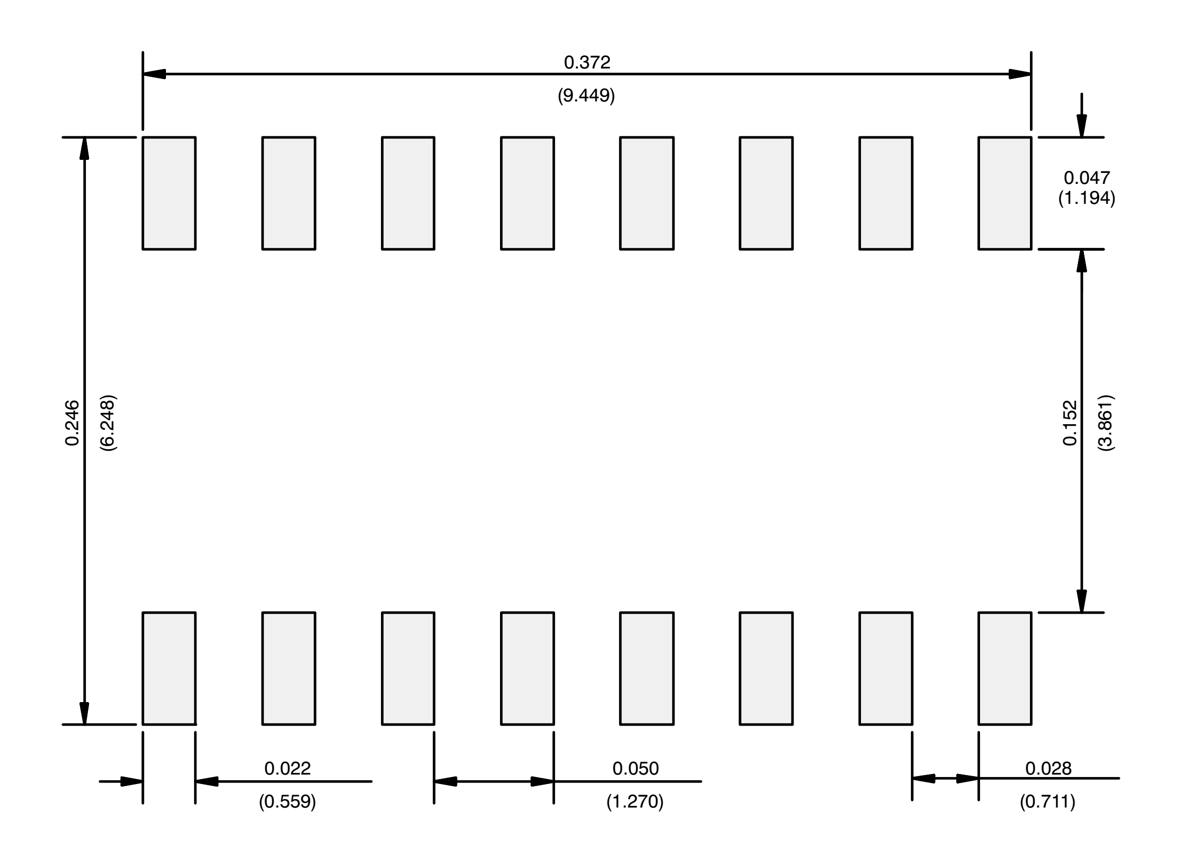
RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)



RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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